100 mA Adjustable Output, Positive Voltage Regulator

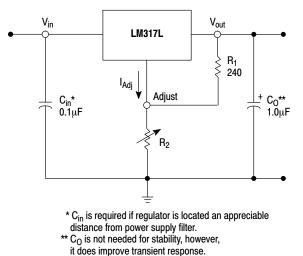
The LM317L is an adjustable 3–terminal positive voltage regulator capable of supplying in excess of 100 mA over an output voltage range of 1.2 V to 37 V. This voltage regulator is exceptionally easy to use and requires only two external resistors to set the output voltage. Further, it employs internal current limiting, thermal shutdown and safe area compensation, making them essentially blow–out proof.

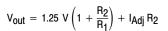
The LM317L serves a wide variety of applications including local, on card regulation. This device can also be used to make a programmable output regulator, or by connecting a fixed resistor between the adjustment and output, the LM317L can be used as a precision current regulator.

Features

- Output Current in Excess of 100 mA
- Output Adjustable Between 1.2 V and 37 V
- Internal Thermal Overload Protection
- Internal Short Circuit Current Limiting
- Output Transistor Safe–Area Compensation
- Floating Operation for High Voltage Applications
- Standard 3–Lead Transistor Package
- Eliminates Stocking Many Fixed Voltages
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable
- These are Pb–Free Devices

Simplified Application





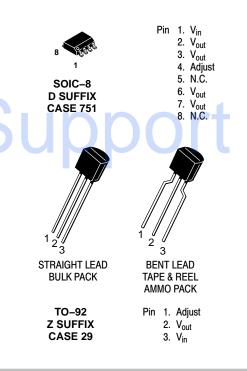
Since I_{Adj} is controlled to less than 100 $\mu A,$ the error associated with this term is negligible in most applications.



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LOW CURRENT THREE-TERMINAL ADJUSTABLE POSITIVE VOLTAGE REGULATOR



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 9 of this data sheet.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Input–Output Voltage Differential	V _I –V _O	40	Vdc
Power Dissipation Case 29 (TO-92) $T_A = 25^{\circ}C$ Thermal Resistance, Junction-to-Ambient Thermal Resistance, Junction-to-Case	Ρ _D R _{θJA} R _{θJC}	Internally Limited 160 83	W °C/W °C/W
Case 751 (SOIC–8) (Note 1) T _A = 25°C Thermal Resistance, Junction–to–Ambient Thermal Resistance, Junction–to–Case	Ρ _D R _{θJA} R _{θJC}	Internally Limited 180 45	W °C/W °C/W
Maximum Junction Temperature	T _{JMAX}	+150	°C
Storage Temperature Range	T _{stg}	-65 to +150	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. SOIC-8 Junction-to-Ambient Thermal Resistance is for minimum recommended pad size. Refer to Figure 24 for Thermal Resistance variation versus pad size.

 This device series contains ESD protection and exceeds the following tests: Human Body Model, 2000 V per MIL STD 883, Method 3015. Machine Model Method, 200 V.

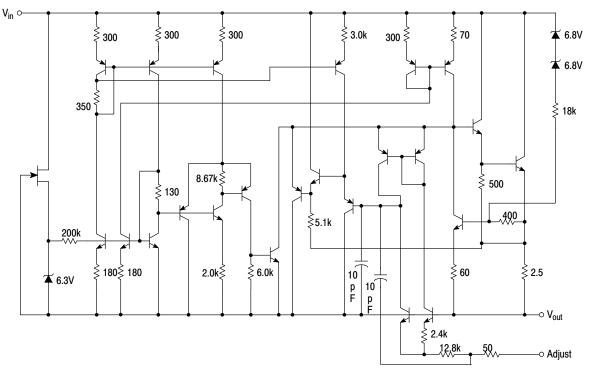


Figure 1. Representative Schematic Diagram

ELECTRICAL CHARACTERISTICS

(V_I-V_O = 5.0 V; I_O = 40 mA; T_J = T_{low} to T_{hinh} (Note 3); I_{max} and P_{max} (Note 4); unless otherwise noted.)

	Figure	Symbol	LM317L, LB, NCV317LB			
Characteristics			Min	Тур	Мах	Unit
Line Regulation (Note 5) $T_A = 25^{\circ}C, \ 3.0 \ V \leq V_I - V_O \leq 40 \ V$	1	Reg _{line}	-	0.01	0.04	%/V
Load Regulation (Note 5), $T_A = 25^{\circ}C$ 10 mA $\leq I_O \leq I_{max} - LM317L$ $V_O \leq 5.0 V$ $V_O \geq 5.0 V$	2	Reg _{load}	- -	5.0 0.1	25 0.5	mV % V _O
Adjustment Pin Current	3	I _{Adj}	_	50	100	μΑ
$\begin{array}{l} \mbox{Adjustment Pin Current Change} \\ \mbox{2.5 V} \leq V_I - V_O \leq 40 \mbox{ V}, \mbox{ P}_D \leq \mbox{P}_{max} \\ \mbox{10 mA} \leq I_O \leq I_{max} - LM317L \end{array}$	1, 2	Δl _{Adj}	-	0.2	5.0	μΑ
$ \begin{array}{l} \mbox{Reference Voltage} \\ \mbox{3.0 V} \leq V_I - V_O \leq 40 \mbox{ V}, \mbox{ P}_D \leq \mbox{P}_{max} \\ \mbox{10 mA} \leq I_O \leq I_{max} - LM317L \end{array} $	3	V _{ref}	1.20	1.25	1.30	V
Line Regulation (Note 5), 3.0 V \leq V _I – V _O \leq 40 V	1	Reg _{line}	_	0.02	0.07	%/V
Load Regulation (Note 5) 10 mA $\leq I_O \leq I_{max} - LM317L$ $V_O \leq 5.0 V$ $V_O \geq 5.0 V$	2	Reg _{load}	- -	20 0.3	70 1.5	mV % V _O
Temperature Stability $(T_{low} \le T_J \le T_{high})$	3	Τ _S	-	0.7	-	% V _O
Minimum Load Current to Maintain Regulation (V _I – V _O = 40 V)	3	I _{Lmin}	-	3.5	10	mA
$ \begin{array}{l} \mbox{Maximum Output Current} \\ V_I - V_O \leq 6.25 \ \mbox{V}, \ \mbox{P}_D \leq \mbox{P}_{max}, \ \mbox{Z Package} \\ V_I - V_O \leq 40 \ \mbox{V}, \ \mbox{P}_D \leq \mbox{P}_{max}, \ \mbox{T}_A = 25^{\circ}\mbox{C}, \ \mbox{Z Package} \end{array} $	3	I _{max}	100 _	200 20		mA
RMS Noise, % of V _O T _A = 25°C, 10 Hz \leq f \leq 10 kHz	-	N	-	0.003	-	% V _O
Ripple Rejection (Note 6) $V_O = 1.2$ V, f = 120 Hz $C_{Adj} = 10 \mu$ F, $V_O = 10.0$ V	4	RR	60 -	80 80		dB
Thermal Shutdown (Note 7)	-	-	_	180	-	°C
Long Term Stability, $T_J = T_{high}$ (Note 8) $T_A = 25^{\circ}C$ for Endpoint Measurements	3	S	-	0.3	1.0	%/1.0 k Hrs.

3. T_{low} to T_{high} = 0° to +125°C for LM317L -40° to +125°C for LM317LB, NCV317LB
4. I_{max} = 100 mA P_{max} = 625 mW
5. Load and line regulation are specified at constant junction temperature. Changes in V_O due to heating effects must be taken into account separately. Pulse testing with low duty cycle is used.
6. C_{Adj}, when used, is connected between the adjustment pin and ground.
7. Thermal characteristics are not subject to production test.
8. Since Long. Torm Stability constant be measured on const during before objected by the production test.

8. Since Long-Term Stability cannot be measured on each device before shipment, this specification is an engineering estimate of average stability from lot to lot.

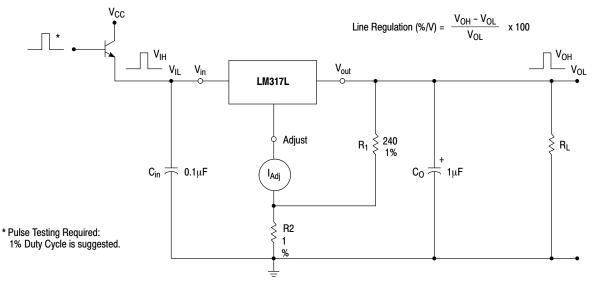


Figure 2. Line Regulation and ΔI_{Adj} /Line Test Circuit

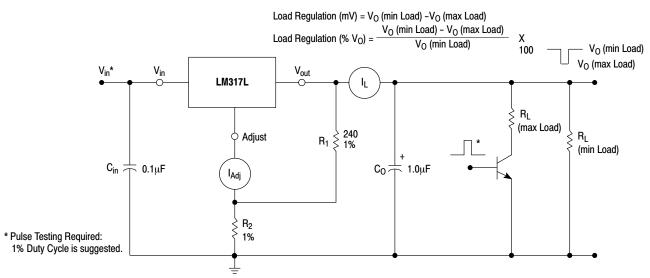
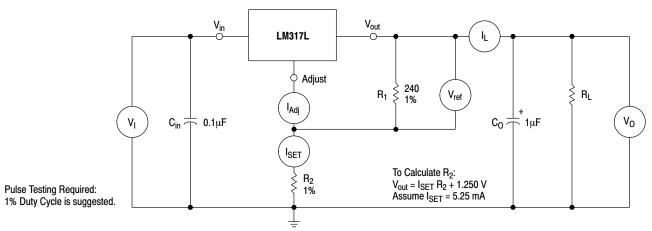
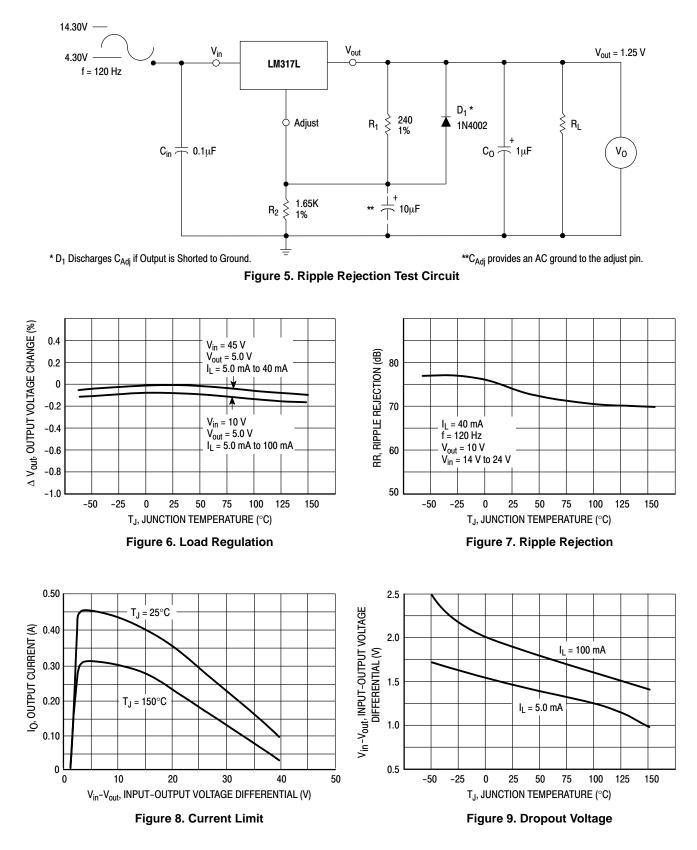
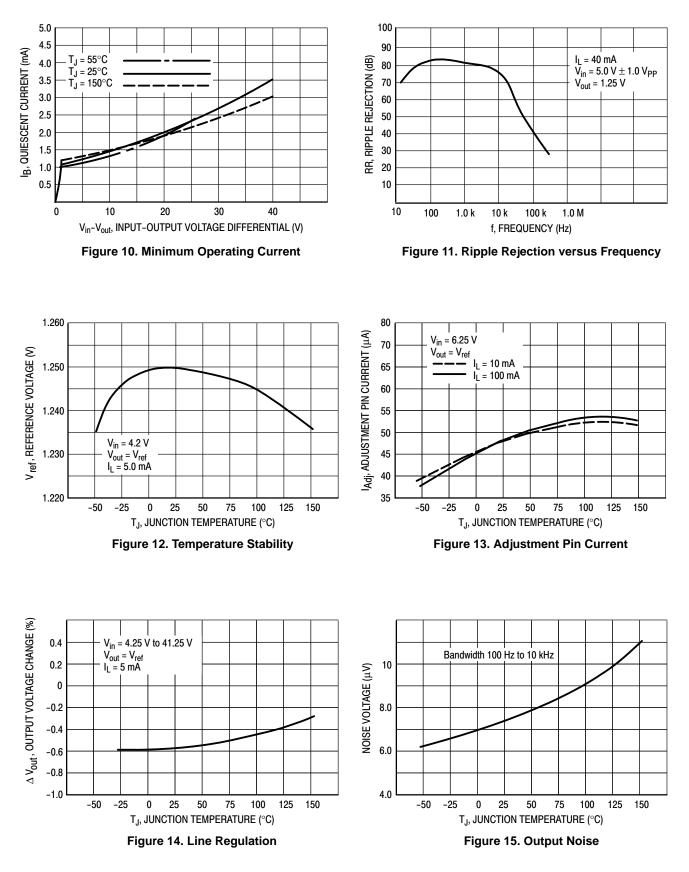


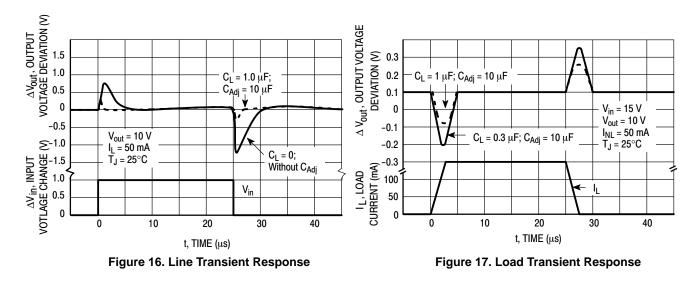
Figure 3. Load Regulation and ΔI_{Adj} /Load Test Circuit











APPLICATIONS INFORMATION

Basic Circuit Operation

The LM317L is a 3-terminal floating regulator. In operation, the LM317L develops and maintains a nominal 1.25 V reference (V_{ref}) between its output and adjustment terminals. This reference voltage is converted to a programming current (I_{PROG}) by R_1 (see Figure 13), and this constant current flows through R_2 to ground. The regulated output voltage is given by:

$$V_{out} = V_{ref} \left(1 + \frac{R_2}{R_1}\right) + I_{Adj} R_2$$

Since the current from the adjustment terminal (I_{Adj}) represents an error term in the equation, the LM317L was designed to control I_{Adj} to less than 100 µA and keep it constant. To do this, all quiescent operating current is returned to the output terminal. This imposes the requirement for a minimum load current. If the load current is less than this minimum, the output voltage will rise.

Since the LM317L is a floating regulator, it is only the voltage differential across the circuit which is important to performance, and operation at high voltages with respect to ground is possible.

Vin LM317L Vout Adjust Vref IPROG Vout I_{Adj} R1 I_{PROG} Vout I_{Adj} R2 Vref = 1.25 V Typical

Figure 18. Basic Circuit Configuration

Load Regulation

The LM317L is capable of providing extremely good load regulation, but a few precautions are needed to obtain maximum performance. For best performance, the programming resistor (R1) should be connected as close to the regulator as possible to minimize line drops which effectively appear in series with the reference, thereby degrading regulation. The ground end of R2 can be returned near the load ground to provide remote ground sensing and improve load regulation.

External Capacitors

A 0.1 μ F disc or 1.0 μ F tantalum input bypass capacitor (C_{in}) is recommended to reduce the sensitivity to input line impedance.

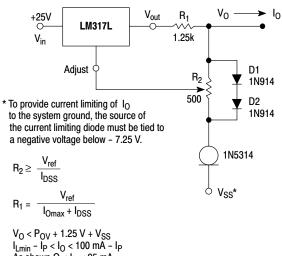
The adjustment terminal may be bypassed to ground to improve ripple rejection. This capacitor (C_{Adj}) prevents ripple from being amplified as the output voltage is increased. A 10 μ F capacitor should improve ripple rejection about 15 dB at 120 Hz in a 10 V application.

Although the LM317L is stable with no output capacitance, like any feedback circuit, certain values of external capacitance can cause excessive ringing. An output capacitance (C_O) in the form of a 1.0 µF tantalum or 25 µF aluminum electrolytic capacitor on the output swamps this effect and insures stability.

Protection Diodes

When external capacitors are used with any IC regulator it is sometimes necessary to add protection diodes to prevent the capacitors from discharging through low current points into the regulator.

Figure 14 shows the LM317L with the recommended protection diodes for output voltages in excess of 25 V or high capacitance values (C_O > 10 $\mu F, \, C_{Adj} > 5.0 \, \mu F).$ Diode D1 prevents Co from discharging thru the IC during an input short circuit. Diode D2 protects against capacitor CAdi discharging through the IC during an output short circuit. The combination of diodes D_1 and D_2 prevents C_{Adj} from discharging through the IC during an input short circuit.



As shown $O < I_O < 95$ mA



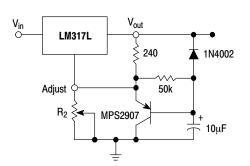


Figure 22. Slow Turn-On Regulator

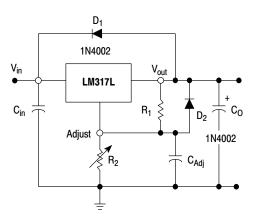
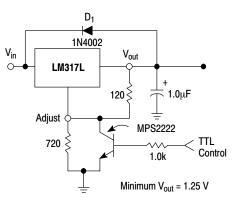
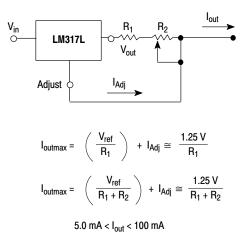


Figure 19. Voltage Regulator with **Protection Diodes**



D₁ protects the device during an input short circuit.

Figure 21. 5.0 V Electronic Shutdown Regulator





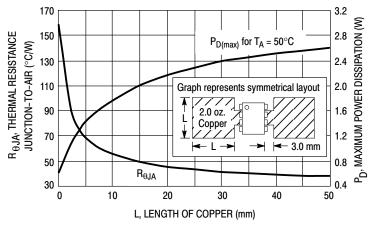


Figure 24. SOP–8 Thermal Resistance and Maximum Power Dissipation versus P.C.B. Copper Length

ORDERING INFORMATION

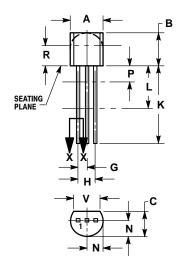
Device	Operating Temperature Range	Package	Shipping [†]
LM317LBDG		SOIC-8 (Pb-Free)	98 Units / Rail
LM317LBDR2G		SOIC-8 (Pb-Free)	2500/Tape & Reel
LM317LBZG		TO-92 (Pb-Free)	2000 Units / Bag
LM317LBZRAG		TO-92 (Pb-Free)	2000 Tape & Reel
LM317LBZRPG	$T_{\rm J} = -40^{\circ}{\rm C}$ to +125°C	TO-92 (Pb-Free)	2000 Ammo Pack
NCV317LBDG*		SOIC-8 (Pb-Free)	98 Units / Rail
NCV317LBDR2G*		SOIC-8 (Pb-Free)	2500/Tape & Reel
NCV317LBZG*		TO-92 (Pb-Free)	2000 Units / Bag
NCV317LBZRAG*		TO-92 (Pb-Free)	2000 Tape & Reel
LM317LDG		SOIC-8 (Pb-Free)	98 Units / Rail
LM317LDR2G		SOIC-8 (Pb-Free)	2500/Tape & Reel
LM317LZG		TO-92 (Pb-Free)	2000 Units / Bag
LM317LZRAG	$T_{\rm J} = 0^{\circ}C \text{ to } +125^{\circ}C$	TO-92 (Pb-Free)	2000 Tape & Reel
LM317LZREG		TO-92 (Pb-Free)	2000 Tape & Reel
LM317LZRMG		TO-92 (Pb-Free)	2000 Ammo Pack
LM317LZRPG	\neg	TO-92 (Pb-Free)	2000 Ammo Pack

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*NCV devices: T_{low} = -40°C, T_{high} = +125°C. Guaranteed by design. NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable.

PACKAGE DIMENSIONS

TO-92 (TO-226) **Z SÙFFIX** CASE 29-11 **ISSUE AM**



STRAIGHT LEAD BULK PACK

D

SECTION X-X

BENT LEAD

TAPE & REEL AMMO PACK

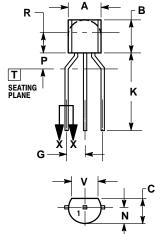
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	INCHES		S MILLIMETE	
DIM	MIN	MAX	MIN	MAX
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
L	0.015	0.020	0.39	0.50
К	0.500		12.70	
L	0.250		6.35	
Ν	0.080	0.105	2.04	2.66
Ρ		0.100		2.54
R	0.115		2.93	
V	0.135		3.43	

- NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: MILLIMETERS. 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED. 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	MILLIMETERS		
DIM	MIN MAX		
Α	4.45	5.20	
В	4.32	5.33	
С	3.18	4.19	
D	0.40	0.54	
G	2.40	2.80	
J	0.39	0.50	
K	12.70		
Ν	2.04	2.66	
Р	1.50	4.00	
R	2.93		
V	3.43		

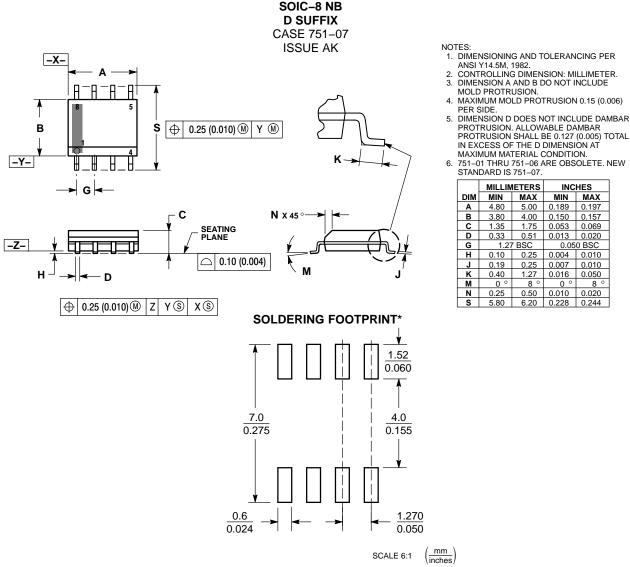




SECTION X-X

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PACKAGE DIMENSIONS



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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